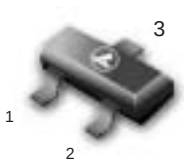
Bias Resistor Transistor

PNP Silicon Surface Mount Transistor with Monolithic Bias Resistor Network

LDTA123YLT1G



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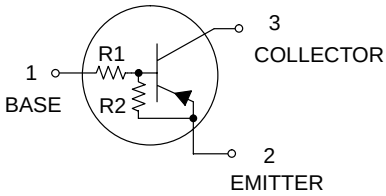
- **Applications**
  Inverter, Interface, Driver

- **Features**
  1) Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistors (see equivalent circuit).
  2) The bias resistors consist of thin-film resistors with complete isolation to allow positive biasing of the input. They also have the advantage of almost completely eliminating parasitic effects.
  3) Only the on/off conditions need to be set for operation, making the device design easy.

- We declare that the material of product compliance with RoHS requirements.



●Absolute maximum ratings (Ta=25°C)

Parameter	Symbol	Limits	Unit
		LDTA123YLT1G	
Supply voltage	V_{CC}	–50	V
Input voltage	V_{IN}	–12 to +5	V
Output current	I_O	–100	mA
	$I_{C(Max.)}$	–100	
Power dissipation	P_D	150	mW
Junction temperature	Tj	150	°C
Storage temperature	Tstg	–55 to +150	°C

DEVICE MARKING AND RESISTOR VALUES

Device	Marking	R1 (K)	R2 (K)	Shipping
LDTA123YLT1G	P8	2.2	10	3000/Tape & Reel
LDTA123YLT3G	P8	2.2	10	10000/Tape & Reel

●Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Input voltage	$V_{I(off)}$	–	–	–0.3	V	V_{CC}=–5V, I_O=–100μA
	$V_{I(on)}$	–3	–	–		V_O=–0.3V, I_O=–20mA
Output voltage	$V_{O(on)}$	–	–0.1	–0.3	V	I_O/I_I=–10mA/–0.5mA
Input current	I_I	–	–	–3.8	mA	V_I=–5V
Output current	$I_{O(off)}$	–	–	–0.5	μA	V_{CC}=–50V, V_I=0V
DC current gain	G_I	33	–	–	–	V_O=–5V, I_O=–10mA
Input resistance	R_1	1.54	2.2	2.86	kΩ	–
Resistance ratio	R_2/R_1	3.6	4.5	5.5	–	–
Transition frequency	f_T *	–	250	–	MHz	V_{CE}=–10V, I_E=5mA, f=100MHz

* Characteristics of built-in transistor

LDTA123YLT1G

●Electrical characteristic curves

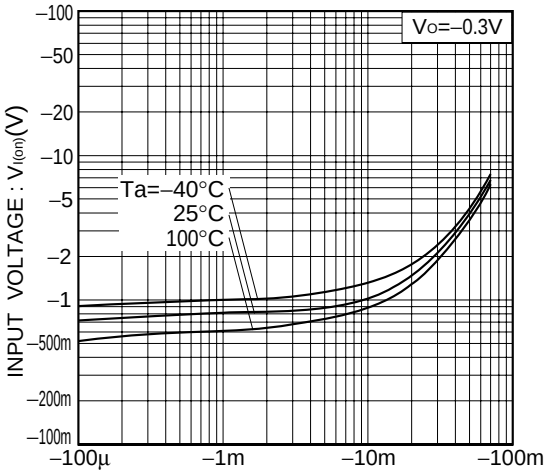


Fig.1 Input voltage vs. output current (ON characteristics)

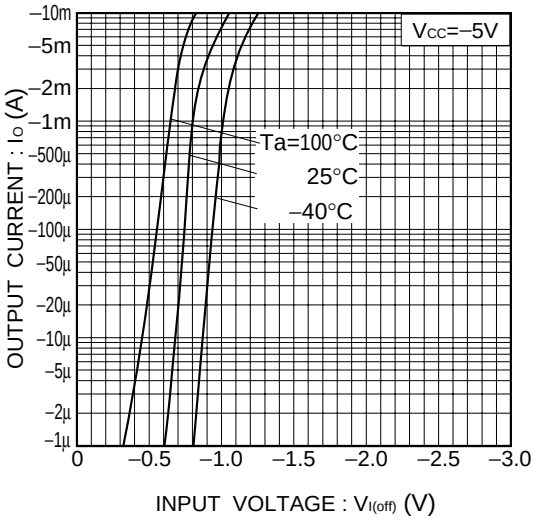


Fig.2 Output current vs. input voltage (OFF characteristics)

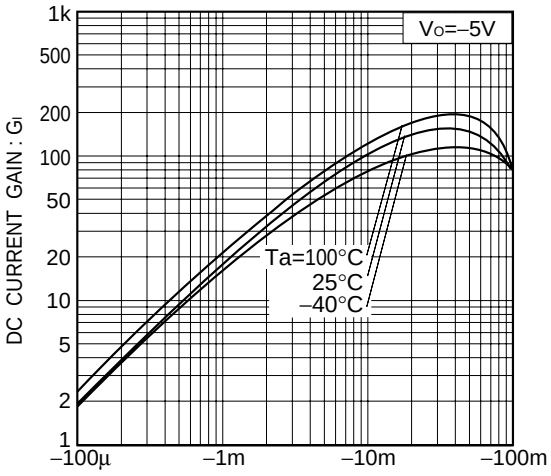


Fig.3 DC current gain vs. output current

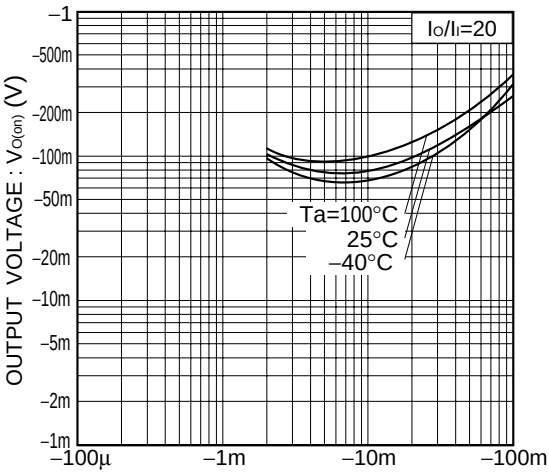


Fig.4 Output voltage vs. output current

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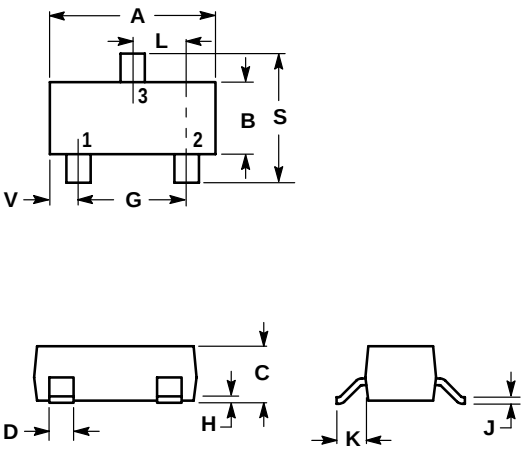

NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M,1982
2. CONTROLLING DIMENSION: INCH.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.1102	0.1197	2.80	3.04
B	0.0472	0.0551	1.20	1.40
C	0.0350	0.0440	0.89	1.11
D	0.0150	0.0200	0.37	0.50
G	0.0701	0.0807	1.78	2.04
H	0.0005	0.0040	0.013	0.100
J	0.0034	0.0070	0.085	0.177
K	0.0140	0.0285	0.35	0.69
L	0.0350	0.0401	0.89	1.02
S	0.0830	0.1039	2.10	2.64
V	0.0177	0.0236	0.45	0.60